

## isc Silicon PNP Power Transistor

# 2SB688

## DESCRIPTION

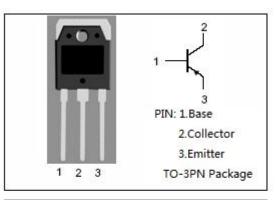
- Collector-Emitter Breakdown Voltage-: V<sub>(BR)CEO</sub>= -120V(Min)
- Good Linearity of hFE
- Complement to Type 2SD718
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

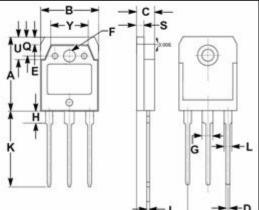
## APPLICATIONS

- Audio frequency power amplifier applications
- Recommend for 45-50W audio frequency amplifier output stage applications

SYMBOL	PARAMETER	PARAMETER VALUE	
V <sub>CBO</sub>	Collector-Base Voltage	-120	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-120	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
lc	Collector Current-Continuous	-8	A
IB	Base Current-Continuous	-0.8	A
Pc	Collector Power Dissipation @ $T_C=25^{\circ}C$	80	W
TJ	Junction Temperature 150		°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C

## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)





R

	m	mm	
DIM	MIN	MAX	
Α	19.60	20.30	
В	15.50	15.70	
С	4.70	4.90	
D	0.90	1.10	
E	1.90	2.10	
F	3.40	3.60	
G	2.90	3.20	
Н	3.20	3.40	
J	0.595	0.605	
Κ	19.80	20.70	
L	1.90	2.20	
N	10.89	10.91	
Q	4.90	5.10	
R	3.35	3.45	
S	1.995	2.100	
U	5.90	6.20	
Y	9.90	10.10	

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## **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -50mA ; I <sub>B</sub> = 0	-120			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -5.0A; I <sub>B</sub> = -0.5A			-2.5	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -5A ; V <sub>CE</sub> = -5V			-1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -120V ; I <sub>E</sub> = 0			-10	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-10	μA
h <sub>FE</sub>	DC Current Gain	Ic= -1A ; Vce= -5V	55		160	
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = -10V; f <sub>test</sub> = 1.0MHz		280		pF
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> =-1A ; V <sub>CE</sub> = -5V		10		MHz

#### h<sub>FE</sub> Classifications

R	0	
55-110	80-160	

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